Drice Each

POWER MOSFETS

SINGLE N-CHANNEL MOSFETs 30V to 60V (CONT.)

						Tape Cut
Mfg. Part No.	Vds	ld	VGS(th)	Rds(on)	Stock No.	1-24+
SOT-223						
● IRFL014TRPBF	60V	2.7A	2V	0.2 ohm @ 10 V	69W7151	
SOT-23						
 SI2300DS-T1-GE3 	30V	3.6A	600mV	0.055 ohm @ 4.5 V	69W7184	0.39
 SI2318DS-T1-GE3 	40V	3A	3V	36 mohm @ 10 V	84R8029	0.50
 SI2308DS-T1-GE3 	60V	2A	3V	125 mohm @ 10 V	84R8024	0.34
● SI2308BDS-T1-E3	60V	2.3A	1V	0.13 ohm @ 10 V	69W7187	0.48
SOT-323						
● SI1330EDL-T1-E3	60V	240mA	2V	1 ohm @ 10 V	69W7174	
TO-220AB		•				
● IRFZ14PBF	60V	10A	2V	0.2 ohm @ 10 V	63J7108	0.96
TO-236						
 SI2304BDS-T1-GE3 	30V	3.2A	3V	105 mohm @ 20 V	16P3704	0.16
 SI2306BDS-T1-GE3 	30V	4A	3V	65 mohm @ 20 V	16P3706	0.14
 SI2316BDS-T1-GE3 	30V	4.5A	3V	80 mohm @ 20 V	16P3710	
● SI2308BDS-T1-GE3	60V	2.3A	3V	0.13 ohm @ 20 V	16P3708	0.20
TO-252						
 SUD50N04-8M8P-GE3 	40V	50A	3V	0.0069 ohm @ 20 V	16P3890	
 SUD23N06-31-GE3 	60V	9.1A	3V	45 mohm @ 20 V	16P3889	0.93
 SUD23N06-31L-E3 	60V	23A	2V	0.025 ohm @ 10 V	06J8438	
TO-263						
 SUM110N06-3M9H-E3 	60V	110A	3.4V	0.00325 ohm @ 10 V	69W7247	
TSOP						
 SI3424BDV-T1-GE3 	30V	7A	3V	23 mohm @ 10 V	84R8033	
 SI3458BDV-T1-GE3 	60V	3.2A	3V	82 mohm @ 10 V	84R8039	

PIM_168148

SILICON CARBIDE (SiC) POWER MOSFETS

- Features

 N-Channel Enhancement Mode
 Industry Leading RDS(on)
 High Speed Switching

- Low Capacitances
 Easy to Parallel
- Simple to Drive

Benefits

- Higher System Efficiency
 Reduced Cooling Requirements
 Avalanche Ruggedness
 Increased System Switching Frequency
 Applications

Applications Solar Inverters



High Voltage DC/DC ConvertersMotor Drives

							Price Each
Mfg. Part No.	Packaging	ld	Vds	Rds(on)	VGS(th)	Stock No.	1-49+
N Channel							
C2M1000170D	TO-247-3	4.9A	1.7kV	0.95ohm	2.4V	08X1011	
C2M0160120D	TO-247-3	17.7A	1.2kV	0.16ohm	2.5V	08X3830	8.33
CMF10120D	TO-247-3	24A	1.2kV	0.16ohm	2.4V	46T8852	
C2M0080120D	TO-247-3	31.6A	1.2kV	0.08ohm	3.2V	67W3046	
					•		

N CHANNEL POWER MOSFETs











	SOIC				
					Price Each
Vds	ld	VGS(th)	Rds(on)	Stock No.	1-9+
20V	5.2A	600mV	25 mohm @ 4.5 V	98H0963	
30V	171A	2V	1.3 mohm @ 10 V	73R4092	0.96
30V	191A	1.5V	0.0013 ohm @ 10 V	09R9666	0.25
30V	191A	1.5V	2 mohm @ 10 V	09R9667	
40V	20A	3V	0.0031 ohm @ 10 V	52T8335	0.41
20V	4A	400mV	60 mohm @ 4.5 V	10N9724	
30V	75A	1.5V	5 mohm @ 10 V	78R7502	0.51
	30V 30V 30V 40V	Vds Id 20V 5.2A 30V 171A 30V 191A 30V 191A 40V 20A	Vds Id VGS(th) 20V 5.2A 600mV 30V 171A 2V 30V 191A 1.5V 30V 191A 1.5V 40V 20A 3V 20V 4A 400mV	Vds Id VGS(th) Rds(on) 20V 5.2A 600mV 25 mohm @ 4.5 V 30V 171A 2V 1.3 mohm @ 10 V 30V 191A 1.5V 0.0013 ohm @ 10 V 30V 191A 1.5V 2 mohm @ 10 V 40V 20A 3V 0.0031 ohm @ 10 V 20V 4A 400mV 60 mohm @ 4.5 V	Vds Id VGS(th) Rds(on) Stock No. 20V 5.2A 600mV 25 mohm @ 4.5 V 98H0963 30V 171A 2V 1.3 mohm @ 10 V 73R4092 30V 191A 1.5V 0.0013 ohm @ 10 V 09R9666 30V 191A 1.5V 2 mohm @ 10 V 09R9667 40V 20A 3V 0.0031 ohm @ 10 V 52T8335 20V 4A 400mV 60 mohm @ 4.5 V 10N9724

N CHANNEL POWER MOSFETs (CONT.)

						Price Each
Mfg. Part No.	Vds	ld	VGS(th)	Rds(on)	Stock No.	1-9+
SOT-223					Y	
● NTF3055L108T1G	60V	3A	1.68V	0.092 ohm @ 5 V	10P1660	0.61
● NTF3055-100T1G	60V	3A	3V	0.088 ohm @ 10 V	10N9573	0.63
SOT-23						
● NTR4501NT1G	20V	3.2A	1.2V	80 mohm @ 4.5 V	06R3476	0.42
TO-220						
NTP6413ANG	100V	42A	4V	25.6 mohm @ 10 V	63R4590	1.57
NTP6412ANG	100V	58A	4V	16.8 mohm @ 10 V	63R4589	
NTP6410ANG	100V	76A	4V	11 mohm @ 10 V	71R6722	2.13
NDF05N50ZG	500V	5A	4.5V	1.25 ohm @ 10 V	71R6685	
TO-247						
MTW32N20EG	200V	32A	4V	75 mohm @ 10 V	26K4667	
TO-251						
NTD4813N-35G	30V	40A	2.5V	13 mohm @ 10 V	27M2724	
TO-252						
 NTD20N03L27T4G 	20V	20A	1.6V	0.023 ohm @ 5 V	10N9715	0.29
 NTD110N02RT4G 	24V	110A	1.5V	4.1 mohm @ 10 V	10N9713	
NTD4863N-1G	25V	8.6A	2.5V	10.2 mohm @ 10 V	75M5213	
NTD4858N-1G	25V	13.6A	2.5V	6.2 mohm @ 10 V	75M5207	
NTD14N03RT4G	25V	14A	1.5V	95 mohm @ 10 V	09R9638	0.17
● NTD4855N-1G	25V	17.7A	2.5V	4.3 mohm @ 10 V	75M5198	
• NTD4808N-1G	30V	63A	2.5V	8 mohm @ 10 V	27M2715	
● NTD5802NT4G	40V	101A	3.5V	4.4 mohm @ 10 V	13P5605	0.37
● NTD3055L170T4G	60V	9A	1.7V	153 mohm @ 5 V	09R9641	
 NTD3055-150T4G 	60V	9A	3V	150 mohm @ 10 V	10N9571	
 NID6002NT4G 	60V	11A	1.85V	210 mohm @ 10 V	09R9604	
 NTD3055L104T4G 	60V	12A	1.6V	0.089 ohm @ 5 V	26K5099	0.59
● NTD3055L104-1G	60V	12A	2V	104 mohm @ 5 V	45J2116	
 NTD3055-094T4G 	60V	12A	2.9V	0.084 ohm @ 10 V	71J7043	0.58
NTD18N06LT4G	60V	18A	1.8V	54 mohm @ 5 V	09R9639	
NTD20N06LT4G	60V	20A	1.6V	39 mohm @ 5 V	10N9716	0.89
 NTD20N06T4G 	60V	20A	2.91V	37.5 mohm @ 10 V	09R9640	0.89
NTD24N06LT4G	60V	24A	1.7V	0.036 ohm @ 5 V	10N9717	0.88
NTD6414ANT4G	100V	32A	4V	30 mohm @ 10 V	63R4580	
NDD05N50ZT4G	500V	4.7A	4.5V	1.25 ohm @ 10 V	63R4558	
TO-263						
NTB45N06LT4G	60V	45A	1.8V	23 mohm @ 5 V	10N9711	
● NTB45N06T4G	60V	45A	2.8V	26 mohm @ 10 V	10N9712	
NTB6413ANT4G	100V	42A	4V	25.6 mohm @ 10 V	63R4576	0.93
• NTB35N15T4G	150V	37A	2.9V	50 mohm @ 10 V	45J2088	
TO-3P						
NDTL03N150CG	1.5kV	2.5A	4V	8 ohm @ 10 V	11X3629	2.19
TO-3PF						20
NDUL03N150CG	1.5kV	2.5A	4V	8 ohm @ 10 V	11X3630	
TSOP						
• NTGS3446T1G	20V	5.1A	850mV	45 mohm @ 4.5 V	04M7521	0.10
WDFN						0.10
NTLJS4114NT1G	30V	7.8A	550mV	0.0203 ohm @ 4.5 V	10N9582	
• NTTFS4824NTAG	30V	20.6A	1.9V	3.7 mohm @ 10 V	08R4035	
PIM_116722						

N-CHANNEL TRENCH MOSFETs







SOT-23

Features

 Low on-state resistance Low figure of merit

Wide package rangeSuitable for a wide range of applications

Rds(on) 8.9mohm	VGS(th)	Stock No. 79R1989	1-24+
8.9mohm	2V	79R1989	
8.9mohm	2V	79R1989	
56mohm	3V	79R1994	
0.2ohm	3V	79R1996	
0.057ohm	3V	79R1997	
	0.2ohm	0.2ohm 3V	0.2ohm 3V 79R1996

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